

DESIGN NOTES

Electronic Circuit Breaker in Small DFN Package Eliminates Sense Resistor – Design Note 402

SH Lim

Introduction

Traditionally, an Electronic Circuit Breaker (ECB) comprises a MOSFET, a MOSFET controller and a current sense resistor. The LTC[®]4213 does away with the sense resistor by using the $R_{DS(ON)}$ of the external MOSFET. The result is a simple, small solution that offers a significant low insertion loss advantage at low operating load voltage. The LTC4213 features two circuit breaking responses to varying overload conditions with three selectable trip thresholds and a high side drive for an external N-channel MOSFET switch.

Overcurrent Protection

The SENSEP and SENSEN pins monitor the load current via the $R_{DS(ON)}$ of the external MOSFET and serve as inputs to two internal comparators—SLOWCOMP and FASTCOMP—with trip points at V_{CB} and $V_{CB(FAST)}$, respectively. The circuit breaker trips when an overcurrent fault causes a substantial voltage drop across the MOSFET. An overload current exceeding $V_{CB}/R_{DS(ON)}$ causes SLOWCOMP to trip the circuit breaker after a 16 μ s delay. In the event of a severe overload or short-circuit current exceeding $V_{CB(FAST)}/R_{DS(ON)}$, the FASTCOMP trips the circuit breaker within 1 μ s, protecting both the MOSFET and the load.

Both of the comparators have a common mode input voltage range from ground to $V_{CC} + 0.2V$. This allows the circuit breaker to operate as the load supply turns on from 0V.

Flexible Overcurrent Setting

The LTC4213 has an I_{SEL} pin to select one of these three overcurrent settings:

I_{SEL} at GND, $V_{CB} = 25mV$ and $V_{CB(FAST)} = 100mV$

I_{SEL} left open, $V_{CB} = 50mV$ and $V_{CB(FAST)} = 175mV$

I_{SEL} at V_{CC} , $V_{CB} = 100mV$ and $V_{CB(FAST)} = 325mV$

Overvoltage Protection

The LTC4213 can provide load overvoltage protection (OVP) above the bias supply. When $V_{SENSEP} > V_{CC} + 0.7V$ for 65 μ s, an internal OVP circuit activates with the GATE pin pulling low and the external MOSFET turning off. The OVP circuit protects the system from an incorrect plug-in event where the V_{IN} load supply is much higher than the V_{CC} bias voltage.

Typical Electronic Circuit Breaker (ECB) Application

Figure 1 shows the LTC4213 in a dual supply ECB application. An input bypass capacitor is recommended to prevent transient spikes when the V_{IN} supply powers-up or the ECB responds to overcurrent conditions. Figure 2 shows a normal power-up sequence. The LTC4213 exits reset mode once the V_{CC} pin is above the internal under voltage lockout threshold and the ON pin rises above 0.8V (see trace 1 in Figure 2). After an internal 60 μ s debounce cycle, the GATE pin capacitance is charged up from ground by an internal 100 μ A current source (see trace 2). As the GATE pin and the gate of MOSFET charges up, the external MOSFET turns on when V_{GATE} exceeds the MOSFET's threshold. The circuit breaker is armed when V_{GATE} exceeds ΔV_{GSARM} , a voltage at which the external MOSFET is deemed fully enhanced and $R_{DS(ON)}$

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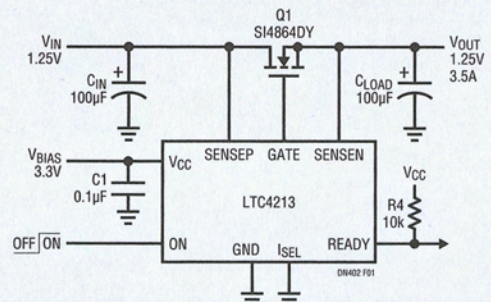


Figure 1. The LTC4213 in an Electronic Circuit Breaker Application

